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74LCX16373 Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

General Description

The LCX16373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable (\overline{OE}) is LOW. When \overline{OE} is HIGH, the outputs are in a high impedance state.

The LCX16373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment.

The LCX16373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

- 5V tolerant inputs and outputs
- 2.3V–3.6V V_{CC} specifications provided
- 5.4 ns t_{PD} max (V_{CC} = 3.3V), 20 μ A I_{CC} max
- Power down high impedance inputs and outputs
- Supports live insertion/withdrawal (Note 1)
- \pm 24 mA output drive (V_{CC} = 3.0V)
- Uses proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

'4LCX16373 Low Voltage 16-Bit Transparent Latch with 5V Tolerant Inputs and Outputs

Note 1: To ensure the high-impedance state during power up or down, $\overline{\text{OE}}$ should be tied to V_{CC} through a pull-up resistor: the minimum value or the resistor is determined by the current-sourcing capability of the driver.

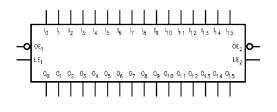
Ordering Code:

Order Number	Package Number	Package Description
74LCX16373G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74LCX16373MEA (Note 3)	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide
74LCX16373MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering code "G" indicates Trays.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

Logic Symbol



74LCX16373

Pin Assignment for SSOP and TSSOP 0E1 48 - LE₁ 47 00. 2 - I₀ 46 01 3 - 4 GND -45 – GND 4 02 44 - 2 5 03 43 • |3 - v_{cc} v_{cc} -42 41 04 -8 - |4 40 0₅ -9 - 1₅ GND -10 39 – GND 38 06 -11 - 1₆ 12 37 0₇ -- I₇ 13 36 08 -- 1₈ 35 09 14 - 19 GND -15 34 — GND 0₁₀ -16 33 - 110 17 32 011-- I_{1 1} 18 31 - v_{cc} V_{CC} 0₁₂ -19 30 - 1₂ 20 29 0₁₃ -**-** |₁₃ GND - 21 28 - GND 27 014 -22 - 1₁₄ 0₁₅ -23 26 - 1₁₅ \overline{OE}_2 24 25 - LE₂ Pin Assignment for FBGA

Connection Diagrams

	1	2	3	4	5	6
ΒΑ		00				
C	-	8	-	-	-	-
	-	ŏ	-	-	-	-
Ш	-	ŏ	-	-	-	-
F	-	ŏ	-	-	_	-
G		0				
н	0	Ο	0	0	0	0
ſ	0	0	0	0	0	0

(Top Thru View)

Pin Descriptions

Pin Names	Description
OEn	Output Enable Input (Active LOW)
LEn	Latch Enable Input
I ₀ —I ₁₅	Inputs
I ₀ -I ₁₅ O ₀ -O ₁₅	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	LE ₁	NC	I ₀
В	0 ₂	0 ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	O ₆	O ₅	GND	GND	I ₅	I ₆
E	0 ₈	0 ₇	GND	GND	۱ ₇	I ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	O ₁₂	O ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
н	0 ₁₄	0 ₁₃	NC	NC	I ₁₃	I ₁₄
J	0 ₁₅	NC	OE ₂	LE ₂	NC	I ₁₅

Truth Tables

	Inputs		Outputs
LE ₁	OE ₁	I ₀ –I ₇	0 ₀ –0 ₇
Х	Н	Х	Z
н	L	L	L
н	L	н	н
L	L	Х	O ₀
	Inputs		Outputs
LE ₂	0E2	I ₈ -I ₁₅	0 ₈ –0 ₁₅
LE ₂ X	OE ₂ H	I ₈ −I ₁₅ ×	0 ₈ -0 ₁₅ Z
Х	Н	X	

H = HIGH Voltage Level

L = LOW Voltage Level X = Immaterial Z = High Impedance

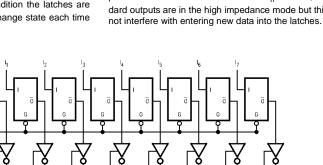
 $O_0 = Previous O_0$ before HIGH-to-LOW transition of Latch Enable

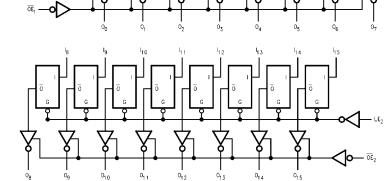
Functional Description

The LCX16373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time

its I input changes. When LE_n is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition of LE_n. The 3-STATE standard outputs are controlled by the Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the standard outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams





Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

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Absolute Maximum Ratings(Note 4)

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Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
VI	DC Input Voltage	-0.5 to +7.0		V
Vo	DC Output Voltage	-0.5 to +7.0	Output in 3-STATE	V
		-0.5 to V _{CC} + 0.5	Output in HIGH or LOW State (Note 5)	v
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50	V _O < GND	mA
		+50	$V_{O} > V_{CC}$	IIIA
I _O	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Recommended Operating Conditions (Note 6)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	$\begin{array}{c c c c c c c c c c c c c c c c c c c $	v	
VI	Input Voltage		0	5.5	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	v
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±24	
				±12	mA
		$V_{CC} = 2.3V - 2.7V$		±8	
Τ _Α	Free-Air Operating Temperature		-40	85	°C
$\Delta t / \Delta V$	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Unused inputs must be held HIGH or LOW. They may not float.

DC Electrical Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
-		Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 - 3.6	2.0		v
V _{IL}	LOW Level Input Voltage		2.3 - 2.7		0.7	V
			2.7 - 3.6		0.8	v
V _{OH} HIGH Level Output Voltage	I _{OH} = -100 μA	2.3 - 3.6	V _{CC} - 0.2			
		I _{OH} = 8 mA	2.3	1.8		
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 - 3.6		0.2	
		$I_{OL} = 8 \text{ mA}$	2.3		0.6	
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	
l _l	Input Leakage Current	$0 \le V_I \le 5.5 V$	2.3 - 3.6		±5.0	μA
l _{oz}	3-STATE Output Leakage	$0 \le V_O \le 5.5 V$	2.3 - 3.6		±5.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$	2.3 - 3.0		±3.0	μΑ
IOFF	Power-Off Leakage Current	$V_1 \text{ or } V_0 = 5.5 \text{V}$	0		10	μA

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}$	Units		
Gymbol	i arameter	Conditions	(V) Min	Max	Units		
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 - 3.6		20	μA	
		$3.6V \le V_I, V_O \le 5.5V$ (Note 7)	2.3 - 3.6		±20	μΛ	
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 - 3.6		500	μA	-
							-1

Note 7: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

		$\mathbf{T}_{\mathbf{A}} = -40^{\circ}\mathbf{C}$ to $+85^{\circ}\mathbf{C}$, $\mathbf{R}_{\mathbf{L}} = 500\Omega$						
Symbol	Parameter	V _{CC} = 3.	$3V \pm 0.3V$	V _{CC} =	= 2.7V	V _{CC} = 2.9	$5V \pm 0.2V$	Units
	Parameter	C _L =	C _L = 50 pF		C _L = 50 pF		C _L = 30 pF	
		Min	Max	Min	Max	Min	Max	-
t _{PHL}	Propagation Delay	1.5	5.4	1.5	5.9	1.5	6.5	ns
t _{PLH}	In to On	1.5	5.4	1.5	5.9	1.5	6.5	115
t _{PHL}	Propagation Delay	1.5	5.5	1.5	6.4	1.5	6.6	ns
t _{PLH}	LE to O _n	1.5	5.5	1.5	6.4	1.5	6.6	115
t _{PZL}	Output Enable Time	1.5	6.1	1.5	6.5	1.5	7.9	ns
t _{PZH}		1.5	6.1	1.5	6.5	1.5	7.9	115
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	ns
t _{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	115
t _S	Setup Time, In to LE	2.5		2.5		3.0		ns
t _H	Hold Time, In to LE	1.5		1.5		2.0		ns
t _W	LE Pulse Width	3.0		3.0		3.5		ns
t _{OSHL}	Output to Output Skew (Note 8)		1.0					ns
t _{OSLH}			1.0					115

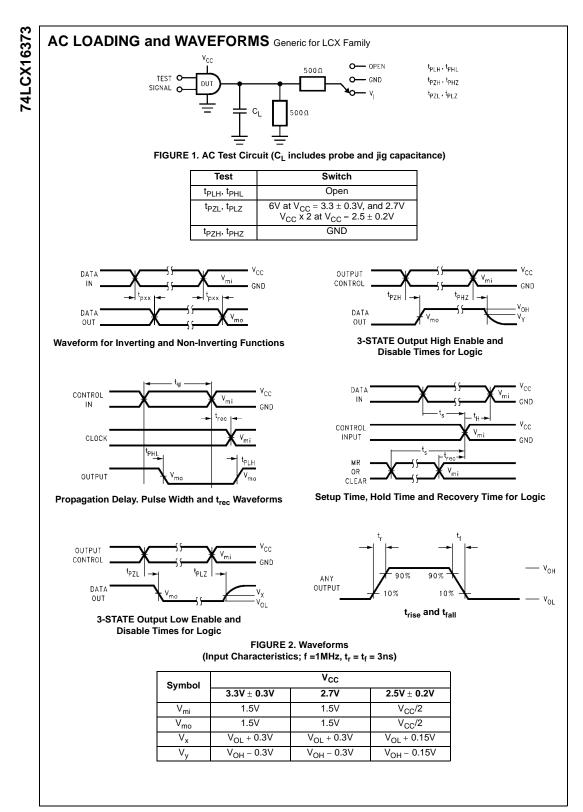
Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

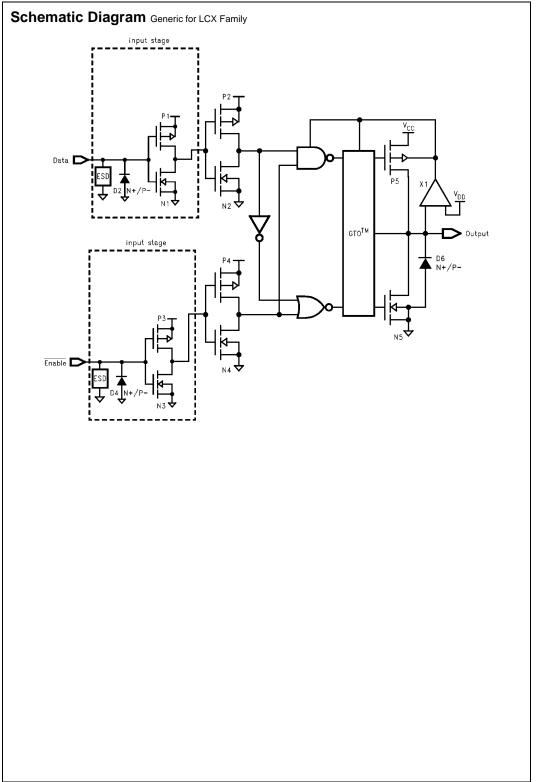
Dynamic Switching Characteristics

Symbol	Parameter	Conditions	v _{cc}	$T_A = 25^{\circ}C$	Units
			(V)	Typical	
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_{L} = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	0.8	V
		$C_L = 30 \text{ pF}, \text{ V}_{IH} = 2.5 \text{V}, \text{ V}_{IL} = 0 \text{V}$	2.5	0.6	v
V _{OLV}	Quiet Output Dynamic Valley VOL	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.8	V
		$C_L=30$ pF, $V_{IH}=2.5V,V_{IL}=0V$	2.5	-0.6	v

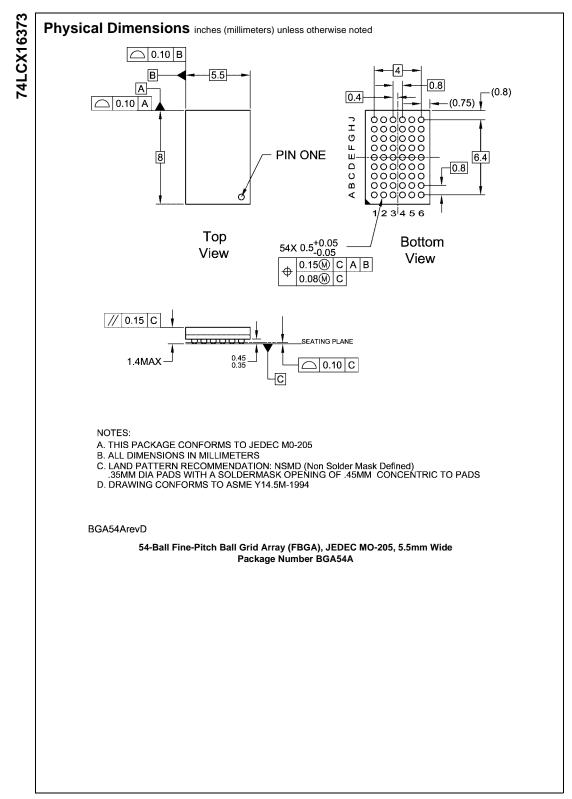
Capacitance

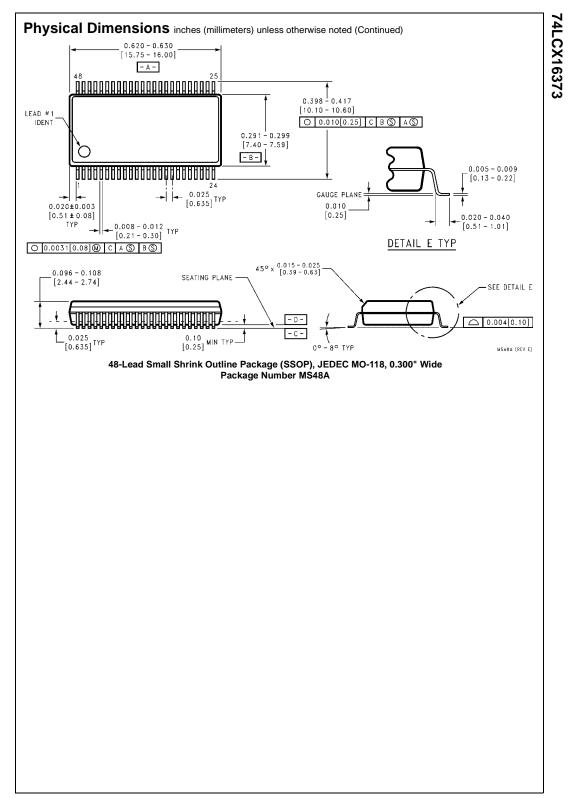
Symbol	Parameter	Conditions	Typical	Units
CIN	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC} , f = 10 MHz	20	pF

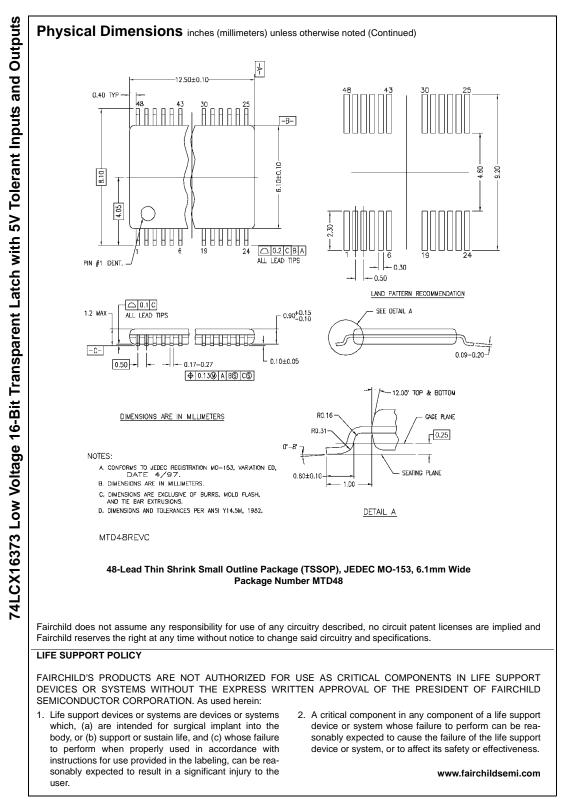




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